

VRRM	IF (TC≤135℃)	QC
650V	6A	9nC

Applications:

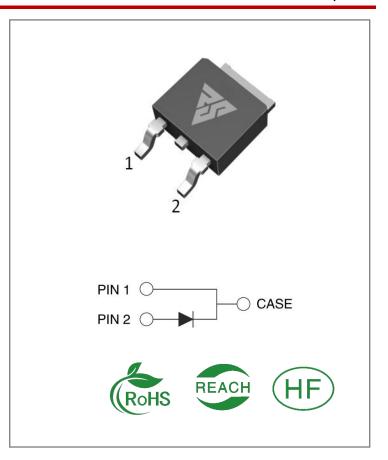
- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Features:

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on VF
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits:

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses



Ordering Information

Part Number	Package	Marking	Packing	Qty.	
RSS04065D	TO-252	RSS04065D	Tape&reel	2500 PCS	



Maximum Ratings (TJ= 25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
VRRM	Repetitive Peak Reverse Voltage	650	V	TC = 25℃	
VRSM	Surge Peak Reverse Voltage	650	٧	TC = 25℃	
VR	DC Blocking Voltage	650	V	TC = 25℃	
IF	Forward Current	13 6 4	А	TC ≤ 25°C TC ≤ 135°C TC ≤ 154°C	
IFRM	Repetitive Peak Forward Surge Current	40	А	TC = 25° C, tp = 8.3ms, Half Sine Wave	
Ptot	Power Dissipation	51	W	TC = 25℃	Fig.3
TC	Maximum Case Temperature	154	$^{\circ}$ C		
TJ,TST G	Operating Junction and Storage Temperature	-55 to175	$^{\circ}$ C		

Electrical Characteristics (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
VF	Forward Voltage	1.4	1.65	V	IF = 4A, TJ = 25°C IF = 4A, TJ = 175°C	Eig 1	
VF	Forward Voltage	1.7	2.3	V	IF = 4A, TJ = 175℃	Fig.1	
IR	ID Downer Comment		10	^	VR = 650V, TJ = 25°C	Fig 2	
IK	Reverse Current	5	100	μΑ	VR = 650V, TJ = 175℃	Fig.2	
		230			VR = 1V, TJ = 25°C, f = 1MHz		
С	Total Capacitance	24	/	pF	VR = 200V, TJ = 25°C, f = 1MHz	Fig.5	
		20			VR = 400V, TJ = 25°C, f = 1MHz		
00	Total Capacitive	9	/	nC	VD -450V	Γ: _~ 1	
QC	Charge	7			VR =650V,	Fig.4	

Thermal Characteristics (TJ= 25 °C unless otherwise specified)

Symbol	Parameter	Тур.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	2.9	°C/W	Fig.6



Typical Feature curve

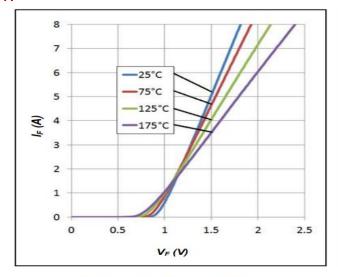


Figure 1. Forward Characteristics

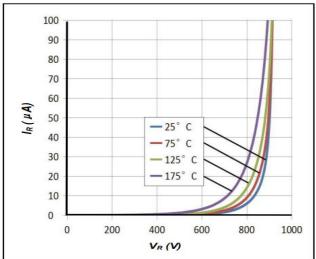


Figure 2. Reverse Characteristics

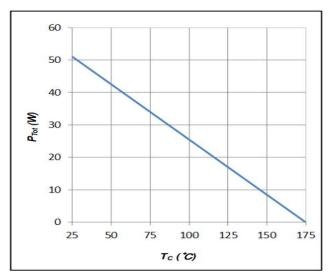


Figure 3. Power Derating

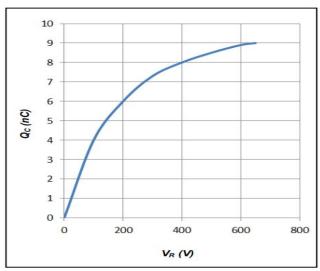


Figure 4. Total Capacitive Charge vs. Reverse Voltage

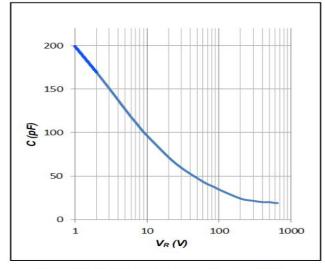


Figure 5. Total Capacitance vs. Reverse Voltage

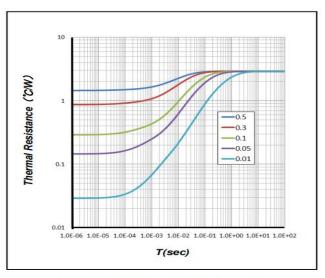
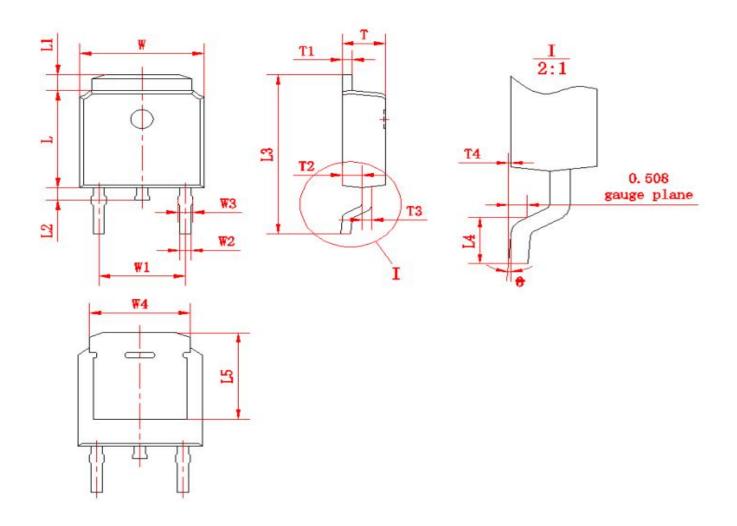


Figure 6. Transient Thermal Impedance

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Package outline drawing(TO-252 Unit: mm)



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符号	Min	Max	初 <i>节</i>	Min	Max	4 2 化	Min	Max
W	6.50	6.70	L1	0.80	1.20	T1	0.48	0.58
W1	(4.572)		L2	0.60	1.00	T2	0.95	1.15
W2	0.6	0.8	L3	9.70 10.30		ТЗ	0.48	0.58
W3	0.68	0.88	L4	1.30	1.70	T4	0.00	0.12
W4	(5	.3)	L5	(5.20)		0	0	8
L	6.00	6.20	Т	2.20 2.40				



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